

VS-GT400TH60N

RoHS

COMPLIANT

Vishay Semiconductors

Molding Type Module IGBT, 2-in-1 Package, 600 V and 400 A



Dual INT-A-PAK

| PRIMARY CHARACTERISTICS | | | | | | |
|---|-----------------|--|--|--|--|--|
| V _{CES} | 600 V | | | | | |
| I_C at T_C = 80 °C | 400 A | | | | | |
| V _{CE(on)} (typical) at I _C = 400 A, 25 °C | 1.60 V | | | | | |
| Speed | 8 kHz to 30 kHz | | | | | |
| Package | Dual INT-A-PAK | | | | | |
| Circuit configuration | Half bridge | | | | | |

FEATURES

- Low $V_{CE(on)}$ trench IGBT technology
- Low switching losses
- 5 µs short circuit capability
- $V_{CE(on)}$ with positive temperature coefficient
- Maximum junction temperature 175 °C
- Low inductance case
- · Fast and soft reverse recovery antiparallel FWD
- Isolated copper baseplate using DCB (Direct Copper Bonding) technology
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- UPS
- Switching mode power supplies
- Electronic welders

DESCRIPTION

Vishay's IGBT power module provides ultralow conduction loss as well as short circuit ruggedness. It is designed for applications such as UPS and SMPS.

| ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted) | | | | | |
|--|--------------------------------|---|--------|------------------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MAX. | UNITS | |
| Collector to emitter voltage | V _{CES} | | 600 | v | |
| Gate to emitter voltage | V _{GES} | | ± 20 | v | |
| Collector ourrent | | T _C = 25 °C | 530 | | |
| Collector current I _C | | T _C = 80 °C | 400 | | |
| Pulsed collector current | I _{CM} ⁽¹⁾ | t _p = 1 ms | 800 | А | |
| Diode continuous forward current | ١ _F | | 400 | | |
| Diode maximum forward current | I _{FM} | | 800 | | |
| Maximum power dissipation | PD | T _J = 175 °C | 1600 | W | |
| Short circuit withstand time | t _{SC} | T _J = 125 °C | 5 | μs | |
| l ² t-value, diode | l ² t | $V_{R} = 0 V, t = 10 ms, T_{J} = 125 \ ^{\circ}C$ | 10 900 | A ² s | |
| RMS isolation voltage | V _{ISOL} | f = 50 Hz, t = 1 min | 2500 | V | |

Note

⁽¹⁾ Repetitive rating: pulse width limited by maximum junction temperature

| IGBT ELECTRICAL SPECIFICATIONS ($T_c = 25$ °C unless otherwise noted) | | | | | | |
|---|----------------------|---|-----|-----|------|----|
| Collector to emitter breakdown voltage | V _{(BR)CES} | $V_{GE} = 0 \text{ V}, \text{ I}_{C} = 2 \text{ mA}, \text{ T}_{J} = 25 ^{\circ}\text{C}$ | 600 | - | - | |
| Collector to emitter saturation voltage | V _{CE(on)} | V_{GE} = 15 V, I _C = 400 A, T _J = 25 °C | - | 1.6 | 2.05 | V |
| | | V_{GE} = 15 V, I _C = 400 A, T _J = 175 °C | - | 2.0 | - | |
| Gate to emitter threshold voltage | V _{GE(th)} | $V_{CE} = V_{GE}$, $I_C = 4$ mA, $T_J = 25$ °C | 4.0 | - | 6.5 | |
| Zero gate voltage collector current | I _{CES} | $V_{CE} = V_{CES}, V_{GE} = 0 \text{ V}, \text{ T}_{J} = 25 ^{\circ}\text{C}$ | - | - | 5.0 | mA |
| Gate to emitter leakage current | I _{GES} | $V_{GE} = V_{GES}, V_{CE} = 0 \text{ V}, \text{ T}_{J} = 25 ^{\circ}\text{C}$ | - | - | 400 | nA |

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| SWITCHING CHARACTERISTICS | S | | | | | |
|--|----------------------|---|------|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Turn-on delay time | t _{d(on)} | | - | 35 | - | |
| Rise time | t _r | | - | 70 | - | - |
| Turn-off delay time | t _{d(off)} | V_{CC} = 400 V, I _C = 400 A, R _g = 1.3 Ω, | - | 180 | - | ns |
| Fall time | t _f | $V_{GE} = \pm 15 \text{ V}, T_{J} = 25 \text{ °C}$ | - | 75 | - | |
| Turn-on switching loss | E _{on} | | - | 14.1 | - | |
| Turn-off switching loss | E _{off} | - | - | 10.0 | - | - mJ |
| Turn-on delay time | t _{d(on)} | | - | 37 | - | |
| Rise time | t _r | | - | 72 | - | - ns |
| Turn-off delay time | t _{d(off)} | V_{CC} = 400 V, I_C = 400 A, R_g = 1.3 Ω, | - | 220 | - | |
| Fall time | t _f | V _{GE} = ± 15 V, T _J = 175 °C | - | 84 | - | |
| Turn-on switching loss | E _{on} | | - | 23.2 | - | |
| Turn-off switching loss | E _{off} | | - | 16.8 | - | mJ |
| Input capacitance | Cies | | - | 30.8 | - | |
| Output capacitance | C _{oes} | V _{GE} = 0 V, V _{CE} = 30 V, f = 1.0 MHz | - | 2.12 | - | nF |
| Reverse transfer capacitance | C _{res} | | - | 0.92 | - | |
| SC data | I _{SC} | $\begin{array}{l} t_{sc} \leq 5 \; \mu s, V_{GE} = 15 \; V, T_J = 125 \; ^{\circ}C, \\ V_{CC} = 360 \; V, V_{CEM} \leq 600 \; V \end{array}$ | - | TBD | - | А |
| Internal gate resistance | R _{gint} | | - | 1.3 | - | Ω |
| Stray inductance | L _{CE} | | - | - | 20 | nH |
| Module lead resistance, terminal to chip | R _{CC'+EE'} | T _C = 25 °C | - | 0.35 | - | mΩ |

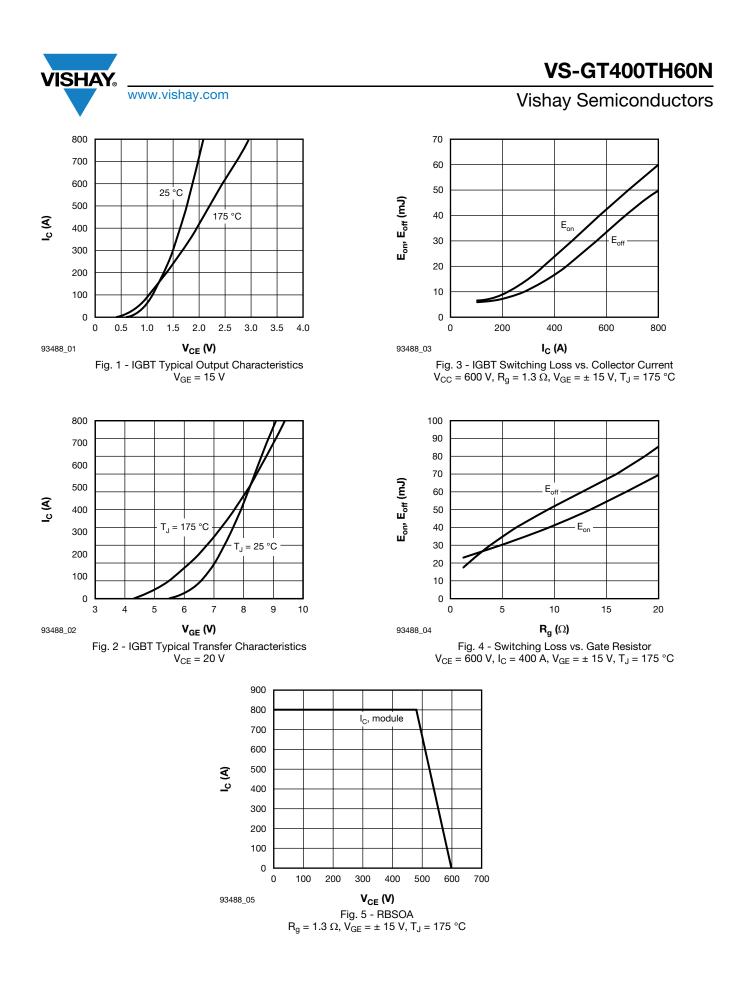
| DIODE ELECTRICAL SPECIFICATIONS ($T_C = 25 \text{ °C}$ unless otherwise noted) | | | | | | | |
|--|-----------------|--|-----------------------------|---|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDIT | TEST CONDITIONS MIN. TYP. M | | | MAX. | UNITS |
| Diode forward voltage | V | I _F = 400 A | T _J = 25 °C | - | 1.38 | 1.80 | - V |
| Didde forward voltage | V _F | I _F = 400 A | T _J = 125 °C | - | 1.41 | - | |
| Diada rayarga ragayany abarga | 0 | Q _{rr} | T _J = 25 °C | - | 15.5 | - | |
| Diode reverse recovery charge | Q _{rr} | | T _J = 125 °C | - | 28.5 | - | μC |
| Diada paale rayaraa raaayar eyeraat | | $I_F = 400 \text{ A}, V_R = 300 \text{ V},$ dI/dt = -7000 A/µs, | T _J = 25 °C | - | 265 | - | ^ |
| Diode peak reverse recovery current | Irr | $V_{GF} = -15 V$ | T _J = 125 °C | - | 335 | - | A |
| | E | E _{rec} | T _J = 25 °C | - | 3.5 | - | ml |
| Diode reverse recovery energy | ⊏rec | | T _J = 125 °C | - | 7.5 | - | mJ |

| THERMAL AND MECHANICAL SPECIFICATIONS | | | | | | | |
|---------------------------------------|----------|-------------------|---------------------------|------|------------|-------|-------|
| PARAMETER | | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Operating junction temperatur | re range | TJ | | - | - | 175 | °C |
| Storage temperature range | | T _{Stg} | | -40 | - | 125 | |
| Junction to case | IGBT | Р | | - | - | 0.094 | |
| per ½ module | Diode | R _{thJC} | | - | - | 0.158 | K/W |
| Case to sink | | R _{thCS} | Conductive grease applied | - | 0.035 | - | |
| Mounting torque | | | Power terminal screw: M6 | | 2.5 to 5.0 | | Nm |
| Mounting torque | | | Mounting screw: M6 | | 3.0 to 5.0 | | |
| Weight | | | | | 300 | | g |

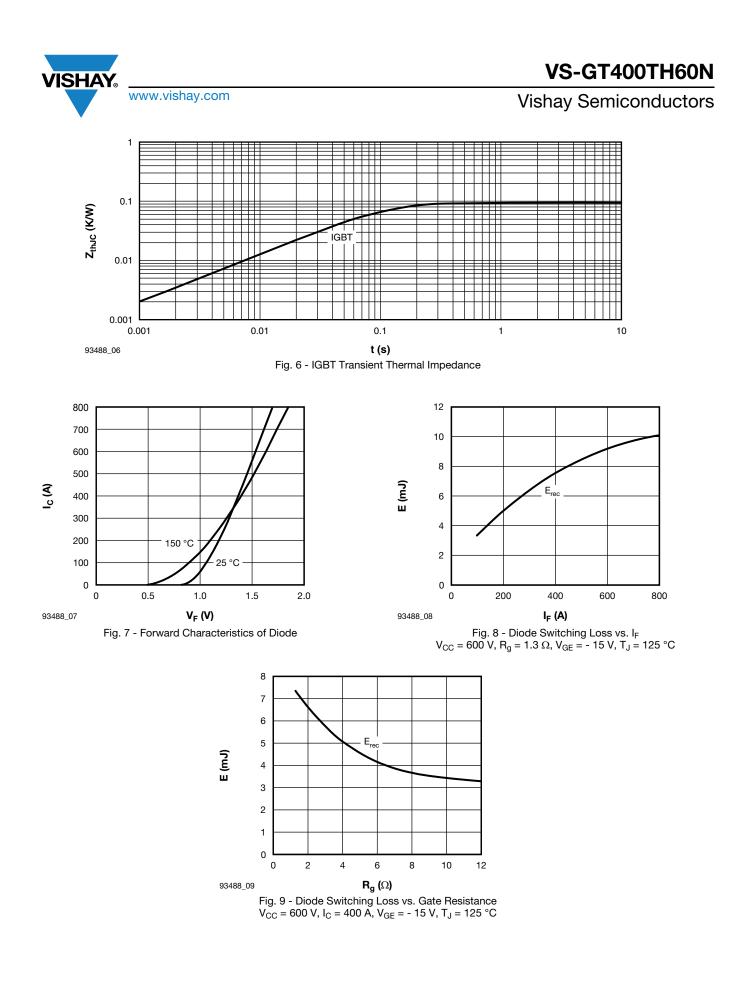
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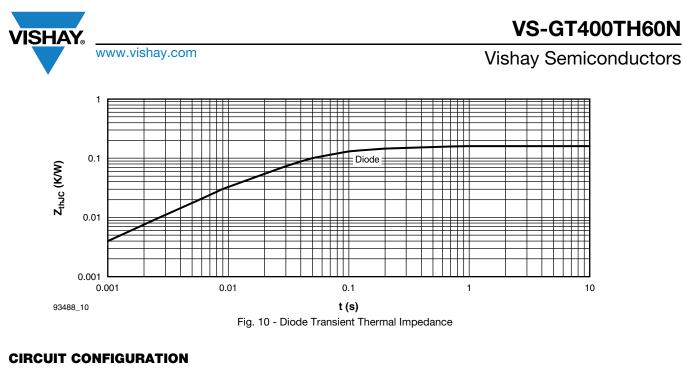
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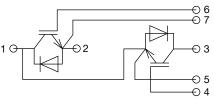


 Revision: 18-Sep-17
 4
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Revision: 18-Sep-17

5

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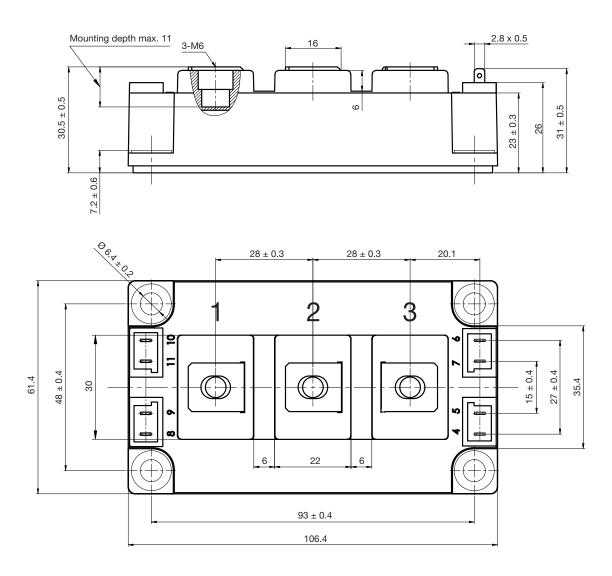


Outline Dimensions

Vishay Semiconductors

Double INT-A-PAK

DIMENSIONS in millimeters (inches)



1

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